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BFG93A; BFG93A/X

NPN 6 GHz wideband transistors

Rev. 05 — 26 November 2007

Product data sheet

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NXP Semiconductors



BFG93A; BFG93A/X

FEATURES

- High power gain
- Low noise figure
- Gold metallization ensures excellent reliability.

APPLICATIONS

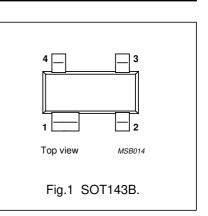
Wideband applications in the UHF and microwave range.

DESCRIPTION

NPN transistor in a 4-pin, dual-emitter SOT143B plastic package.

PINNING

PIN	DESCRIPTION			
BFG93A				
1	collector			
2	base			
3	emitter			
4	emitter			
BFG93A/X				
1	collector			
2	emitter			
3	base			
4	emitter			



MARKING

TYPE NUMBER	CODE
BFG93A	R8%
BFG93A/X	%MX

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-	15	V
V _{CEO}	collector-emitter voltage	open base	-	-	12	V
I _C	collector current (DC)		-	-	35	mA
P _{tot}	total power dissipation	$T_s \le 85 \ ^{\circ}C$	-	-	300	mW
C _{re}	feedback capacitance	$I_{C} = i_{c} = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.6	-	pF
f _T	transition frequency	I _C = 30 mA; V _{CE} = 5 V; f = 500 MHz	4.5	6	-	GHz
G _{UM}	maximum unilateral power gain	I_C = 30 mA; V_{CE} = 8 V; T_{amb} = 25 °C; f = 1 GHz	-	16	-	dB
		$I_C = 30 \text{ mA}; V_{CE} = 8 \text{ V}; T_{amb} = 25 \text{ °C};$ f = 2 GHz	-	10	-	dB
F	noise figure	$ \begin{aligned} \Gamma_{s} &= \Gamma_{opt}; \ \textbf{I}_{C} &= 5 \ \text{mA}; \ \textbf{V}_{CE} &= 8 \ \textbf{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \textbf{f} &= 1 \ \text{GHz} \end{aligned} $	-	1.7	-	dB

BFG93A; BFG93A/X

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	15	V
V _{CEO}	collector-emitter voltage	open base	-	12	V
V _{EBO}	emitter-base voltage	open collector	-	2	V
I _C	collector current (DC)		_	35	mA
P _{tot}	total power dissipation	$T_s \le 85 \ ^{\circ}C$; note 1	-	300	mW
T _{stg}	storage temperature range		-65	+150	°C
Tj	junction operating temperature		_	175	°C

Note

1. T_s is the temperature at the soldering point of the collector pin.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	note 1	290	K/W

Note

1. T_s is the temperature at the soldering point of the collector pin.

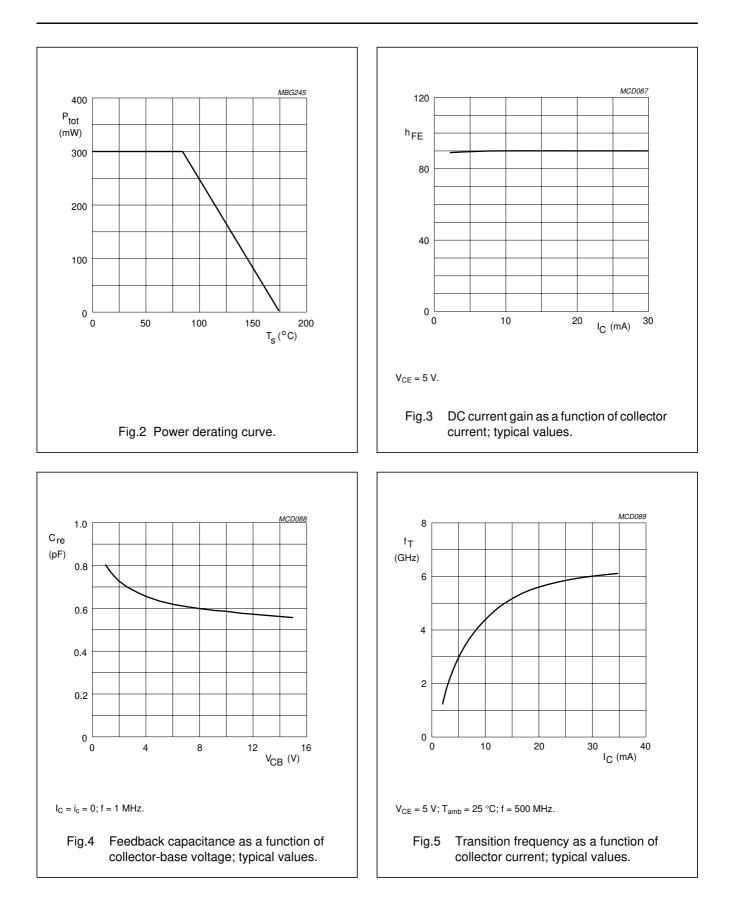
CHARACTERISTICS

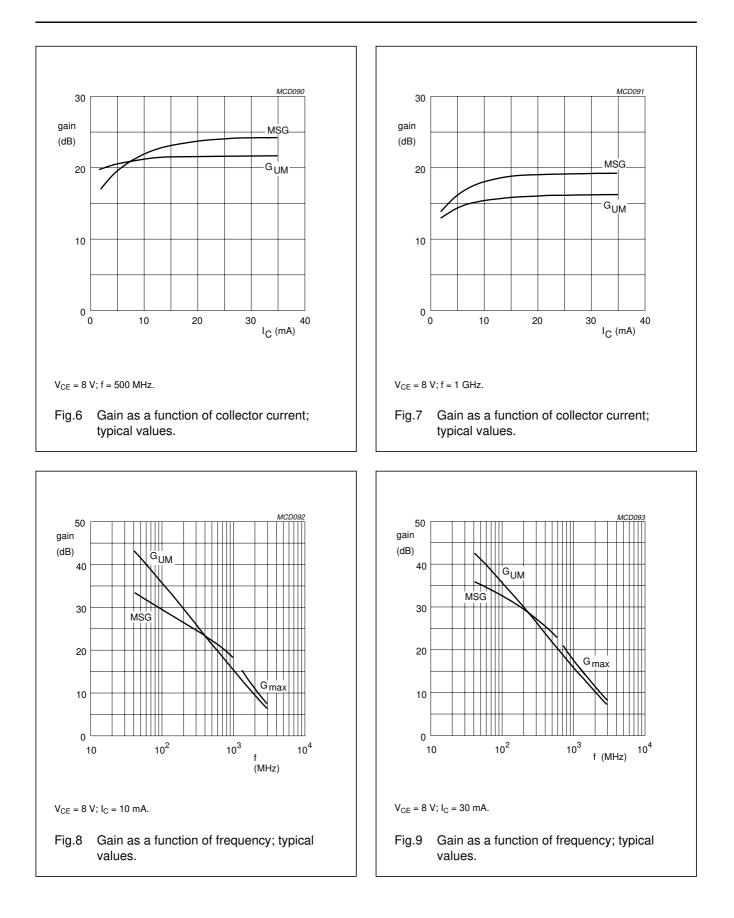
 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

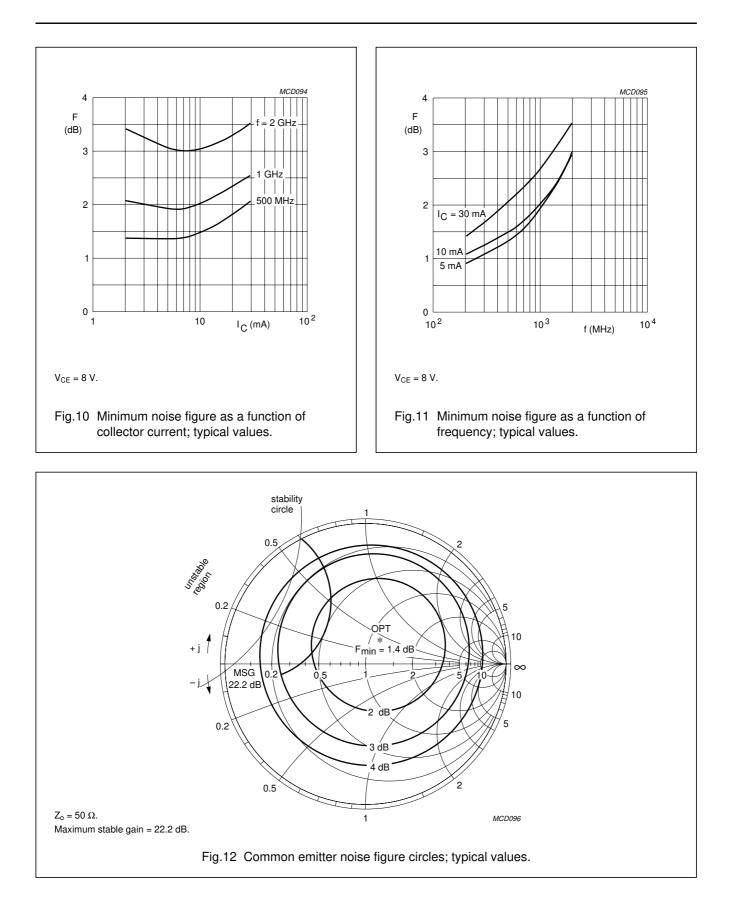
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector leakage current	$I_E = 0; V_{CB} = 5 V$	-	-	50	nA
h _{FE}	DC current gain	$I_{C} = 30 \text{ mA}; V_{CE} = 5 \text{ V}$	40	90	-	
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.9	-	pF
Ce	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 5 V; f = 1 MHz$	-	1.9	-	pF
C _{re}	feedback capacitance	$I_{C} = i_{c} = 0; V_{CB} = 5 V; f = 1 MHz$	-	0.6	-	pF
f _T	transition frequency	$I_{C} = 30 \text{ mA}; V_{CE} = 5 \text{ V}; f = 500 \text{ MHz}$	4.5	6	-	GHz
G _{UM}	maximum unilateral power gain; note 1	I_C = 30 mA; V_{CE} = 8 V; T_{amb} = 25 °C; f = 1 GHz	-	16	-	dB
		I_C = 30 mA; V_{CE} = 8 V; T_{amb} = 25 °C; f = 2 GHz	-	10	-	dB
F	noise figure	$ \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ \text{I}_{C} = 5 \ \text{mA}; \ \text{V}_{CE} = 8 \ \text{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \text{f} = 1 \ \text{GHz} \end{split} $	-	1.7	-	dB
		$ \begin{split} \Gamma_{s} &= \Gamma_{opt}; \ \text{I}_{C} = 5 \ \text{mA}; \ \text{V}_{CE} = 8 \ \text{V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ \text{f} = 2 \ \text{GHz} \end{split} $	_	2.3	-	dB

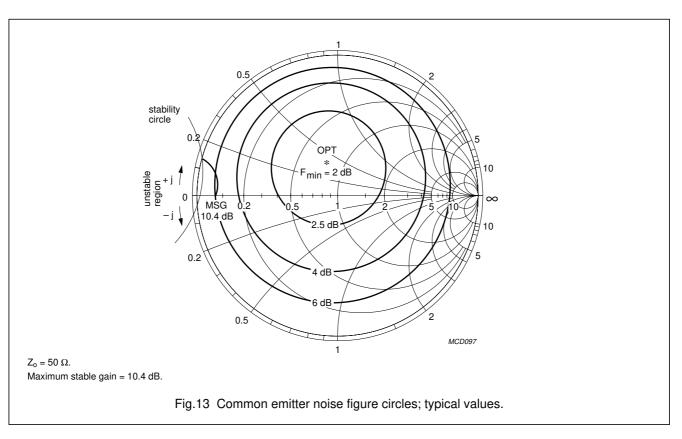
Note

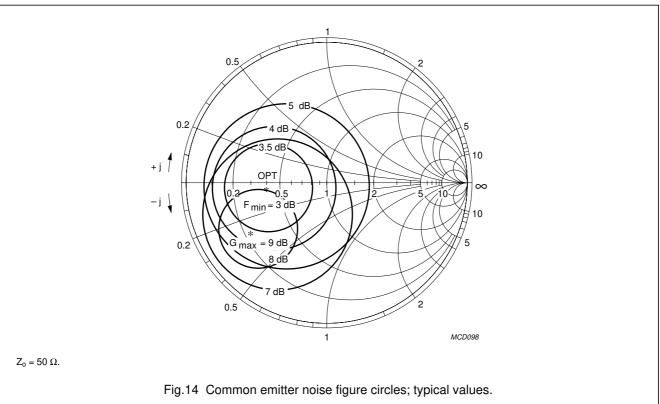
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB.$

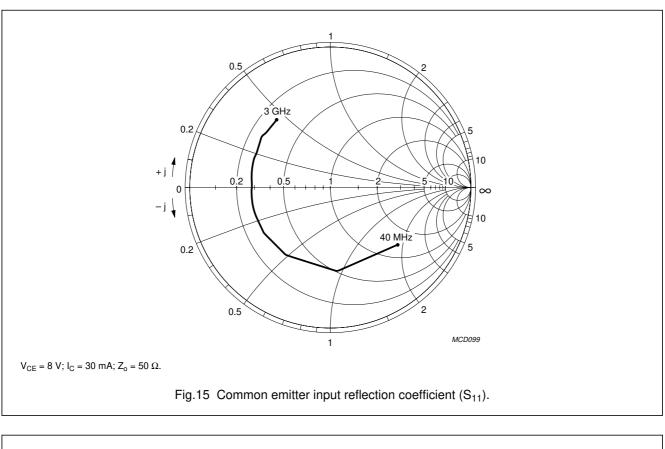


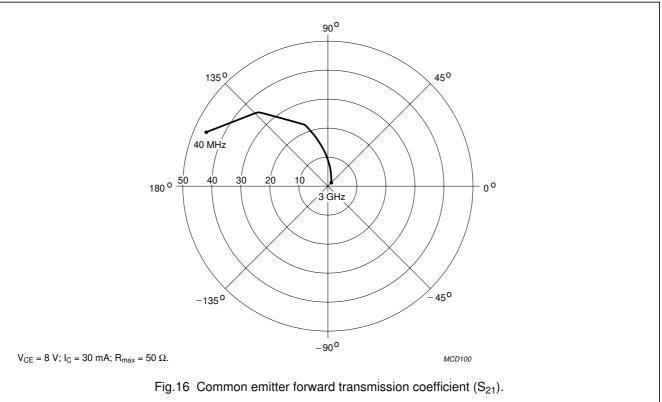


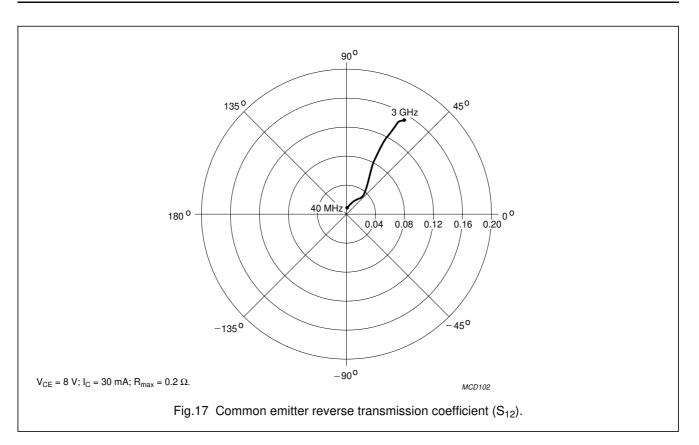


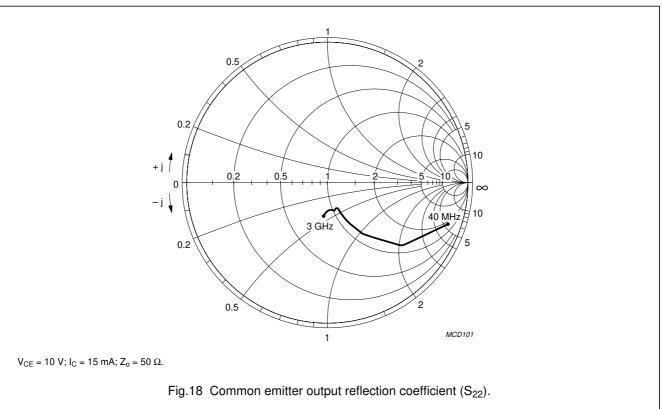












BFG93A; BFG93A/X

SPICE parameters for BFR91A(/X) die

SEQUENCE No.	PARAMETER	VALUE	UNIT
1	IS	1.328	fA
2	BF	102.0	_
3	NF	1.000	_
4	VAF	51.90	V
5	IKF	8.155	А
6	ISE	13.90	fA
7	NE	15.12	_
8	BR	17.69	_
9	NR	994.0	m
10	VAR	3.280	V
11	IKR	10.00	А
12	ISC	1.043	aA
13	NC	1.189	_
14	RB	10.00	Ω
15	IRB	1.000	μA
16	RBM	10.00	Ω
17	RE	763.6	mΩ
18	RC	9.000	Ω
19 (note 1)	ХТВ	0.000	_
20 (note 1)	EG	1.110	EV
21 (note 1)	ХТІ	3.000	_
22	CJE	2.032	pF
23	VJE	600.0	mV
24	MJE	290.0	m
25	TF	6.557	ps
26	XTF	38.97	_
27	VTF	10.93	V
28	ITF	521.0	mA
29	PTF	0.000	deg
30	CJC	1.003	pF
31	VJC	340.8	mV
32	MJC	194.2	m
33	XCJC	120.0	m
34	TR	3.073	ns
35 (note 1)	CJS	0.000	F

SEQUENCE No.	PARAMETER	VALUE	UNIT
36 (note 1)	VJS	750.0	mV
37 (note 1)	MJS	0.000	-
38	FC	800.0	m

Note

1. These parameters have not been extracted, the default values are shown.

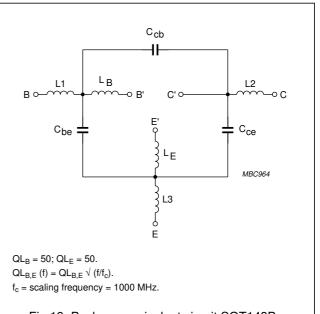


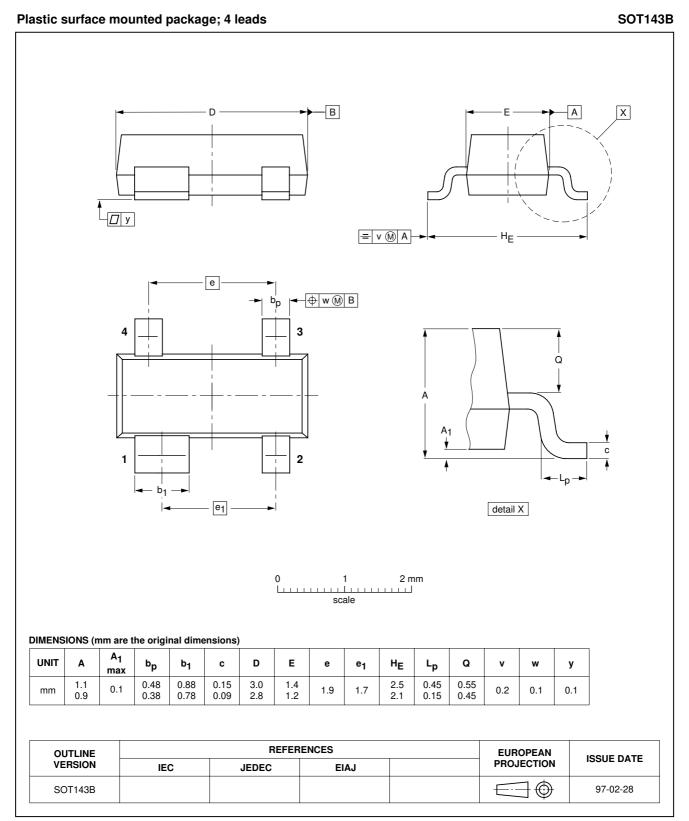
Fig.19 Package equivalent circuit SOT143B.

List of components (see Fig.19)

DESIGNATION	VALUE	UNIT
C _{be}	84	fF
C _{cb}	17	fF
C _{ce}	191	fF
L1	0.12	nH
L2	0.21	nH
L3	0.06	nH
L _B	0.95	nH
LE	0.40	nH

BFG93A; BFG93A/X

PACKAGE OUTLINE



Legal information

Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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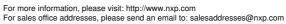
Revision history

Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BFG93A_X_N_5	20071126	Product data sheet	-	BFG93A_X_4	
Modifications:	 Marking tab 	le on page 2; changed code			
BFG93A_X_4 (9397 750 04351)	19980923	Product specification	-	BFG93SERIES_3	
BFG93SERIES_3	19950925	Product specification	-	BFG93SERIES_2	
BFG93SERIES_2	-	Product specification	-	BFG93_SERIES_1	
BFG93_SERIES_1	-	-	-	-	

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